

## An Introduction to zener diodes

Solid state voltage regulator diodes or Zeners have been popular since the late 1950' s when they replaced bulky vacuum tubes. Discrete zeners ranging from 500 mW to 5 watts or less have particularly remained a commonly used semiconductor product, despite the evolution of integrated circuits. High power zeners above 5 watts have increasingly been replaced by regulator ICs for power supply outputs, nevertheless power zeners are still used in a variety of areas.

A zener diode is a specially processed single PN junction that provides relatively constant voltage across two terminal despite changes in zener current. Because of this unique characteristic, it is used as a voltage regulator when placed in parallel across a load to be regulated. In special compensated multiple PN junction configurations, it may also be used as a "Zero-TC" reference voltage

diode for very small changes in voltage over a wide operating temperature range. Other zener configurations for transient suppression have also evolved into their own specialized design features. These have been identified as Transient Voltage Suppressors described separately in the MCC Note D001 series.

Discrete zeners provide optimum versatility in many applications with significant levels of dc and transient power capability compared to those designed into application specific integrated circuits. These devices are typically available up to 200 volts and dc power levels to 50 watts or higher. Transient power capabilities are significantly higher.

A zener diode is operated in reverse bias for normal

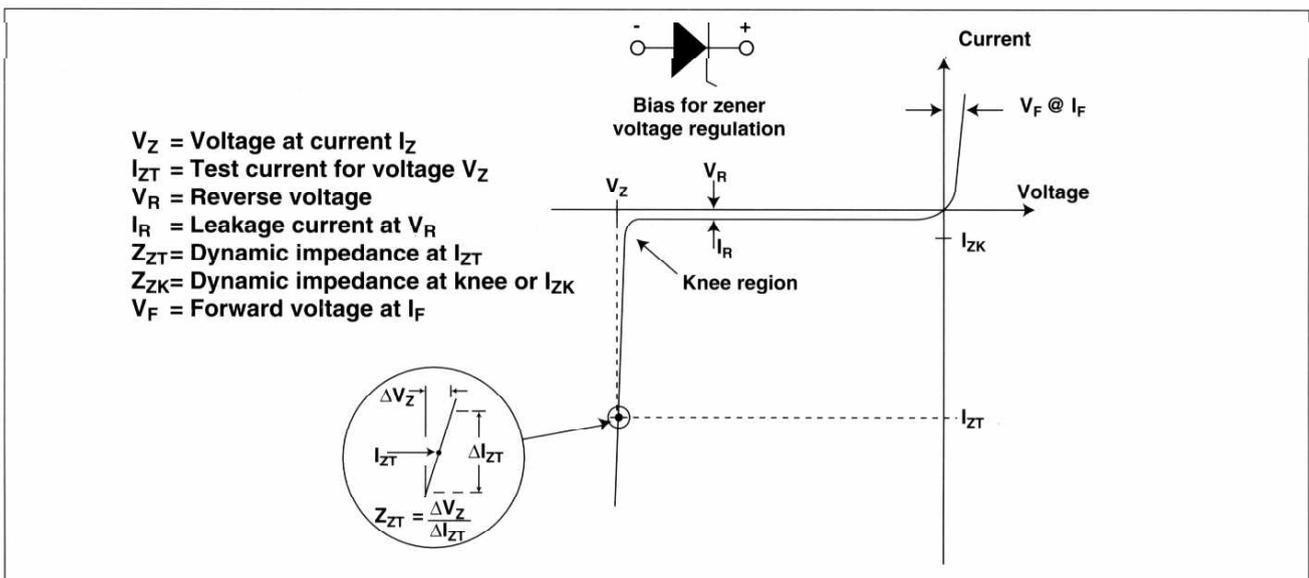


Figure 1. Zener Characteristics and Parameters

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voltage regulation. When sufficient reverse voltage is applied (cathode end biased positively), the zener is driven into its reverse breakdown avalanche mode of operation. This is usually displayed in the third quadrant of a diode current-voltage relation as shown in Figure 1. The initial transition into avalanche breakdown is often called the "knee" region, only minor change in voltage ( $V_z$ ) will occur as further increases in operating current ( $I_z$ ) occur. When applied voltage is still below the avalanche region of the zener, leakage current ( $I_R$ ) is very low typically less than a microamp. In the forward voltage direction (first quadrant), the voltage is comparatively low for current flow similar to rectifiers.

A measure of the voltage regulation capability is called dynamic impedance ( $Z_z$ ) in ohms which equates to the quotient of  $V_z / I_z$  at a given operating current  $I_z$ . The lower this value in ohms, the better the voltage regulation of a zener diode. Zeners will experience some operating current

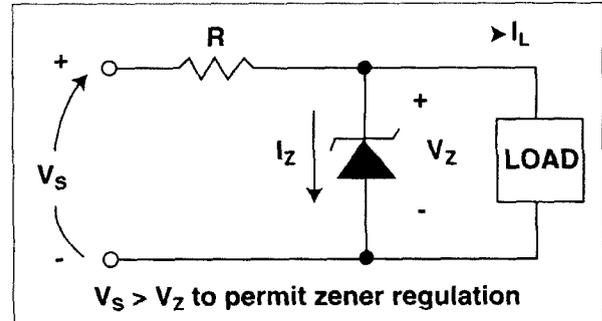


Figure 2. Typical Zener Circuit Application

fluctuations in typical applications, since it is powered by a higher unregulated voltage source as shown in Figure 2. The operating current  $I_z$  is determined by a resistor value  $R$  placed between the zener and the higher voltage source by:

$$I_z = [(V_s - V_z) / R] - I_L$$

where  $V_s$  is the higher unregulated voltage source and  $I_L$  is the current through the load.

When dynamic impedance is specified at the rated test current ( $I_{zT}$ ) for voltage  $V_z$ , it is called  $Z_{zK}$ . This latter value of  $Z_{zK}$  is always higher in ohms compared to  $Z_{zT}$  since it is closer to the transition knee region of the device. At operating currents as described in MCC Note C002. Temperature and applied power also influence zener voltage. These will be further described in MCC Note C002. Temperature and applied power also influence zener voltage. These will be further described in MCC Note C003 and C004 for zener diodes.